

RJK03E5DPA

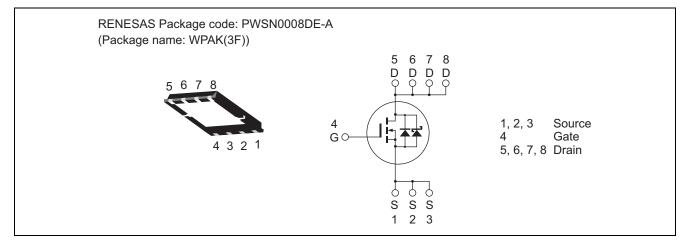
 $30V, 40A, 3.9m\Omega$ max. Built in SBD N Channel Power MOS FET High Speed Power Switching

R07DS0946EJ0400 Rev.4.00 Mar 22, 2013

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

Item	Symbol	Ratings	$(Ta = 25^{\circ}C)$ Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±12	V
Drain current		40	A
Drain peak current	Note1	160	Α
Body-drain diode reverse drain current	I _{DR}	40	А
Avalanche current	I _{AP} Note 2	15	А
Avalanche energy	E _{AR} Note 2	22.5	mJ
Channel dissipation	Pch Note3	35	W
Channel to case thermal impedance	θch-c ^{Note3}	3.57	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	٥C

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle \leq$ 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. Tc = 25°C



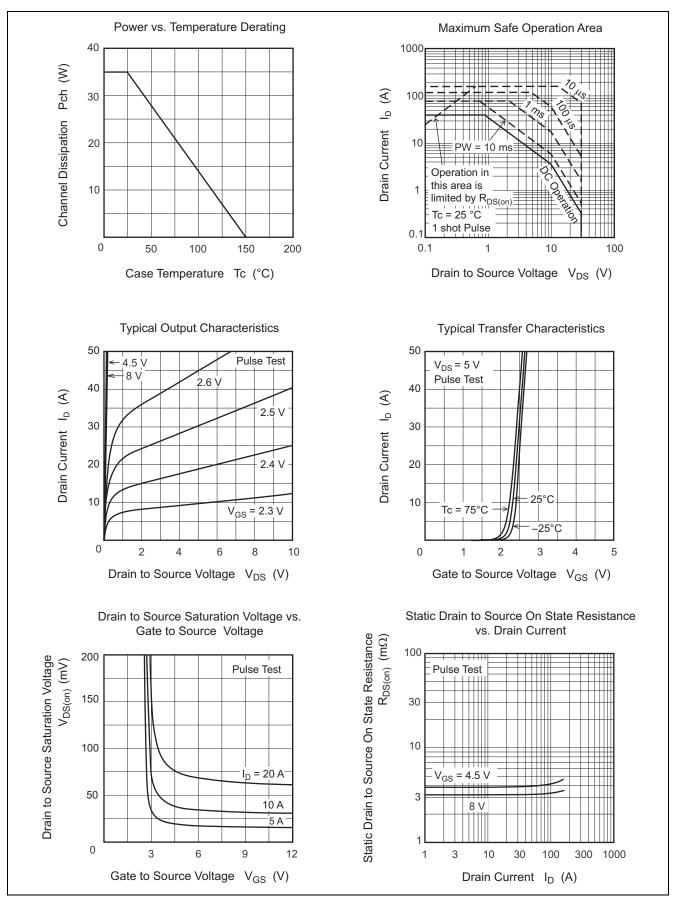
Electrical Characteristics

			-			$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	—		V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	—	±0.1	μΑ	$V_{GS} = \pm 12 V, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	—	_	1	mA	$V_{DS} = 30 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	3.2	3.9	mΩ	$I_D = 20A, V_{GS} = 8.0 V^{Note4}$
resistance	R _{DS(on)}	_	3.8	4.7	mΩ	$I_D = 20A, V_{GS} = 4.5 V^{Note4}$
Forward transfer admittance	y _{fs}	_	98	_	S	$I_D = 20A, V_{DS} = 5 V^{Note4}$
Input capacitance	Ciss	_	3370	4720	pF	V _{DS} = 10 V
Output capacitance	Coss	_	400	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss		250		pF	f = 1 MHz
Gate Resistance	Rg	_	1.8	3.6	Ω	
Total gate charge	Qg	_	25.5	_	nC	V _{DD} = 10 V
Gate to source charge	Qgs		8.5	_	nC	V _{GS} = 4.5 V I _D = 40 A
Gate to drain charge	Qgd	_	6.8	_	nC	
Turn-on delay time	t _{d(on)}		16		ns	V _{GS} = 8 V, I _D = 20 A
Rise time	tr		7		ns	
Turn-off delay time	t _{d(off)}		63		ns	
Fall time	t _f		10	_	ns	
Body-drain diode forward voltage	V _{DF}	_	0.39		V	$I_F = 2 A, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery	t _{rr}	_	26		ns	$I_{F} = 40 \text{ A}, V_{GS} = 0$
time						di _F / dt = 100 A/ µs

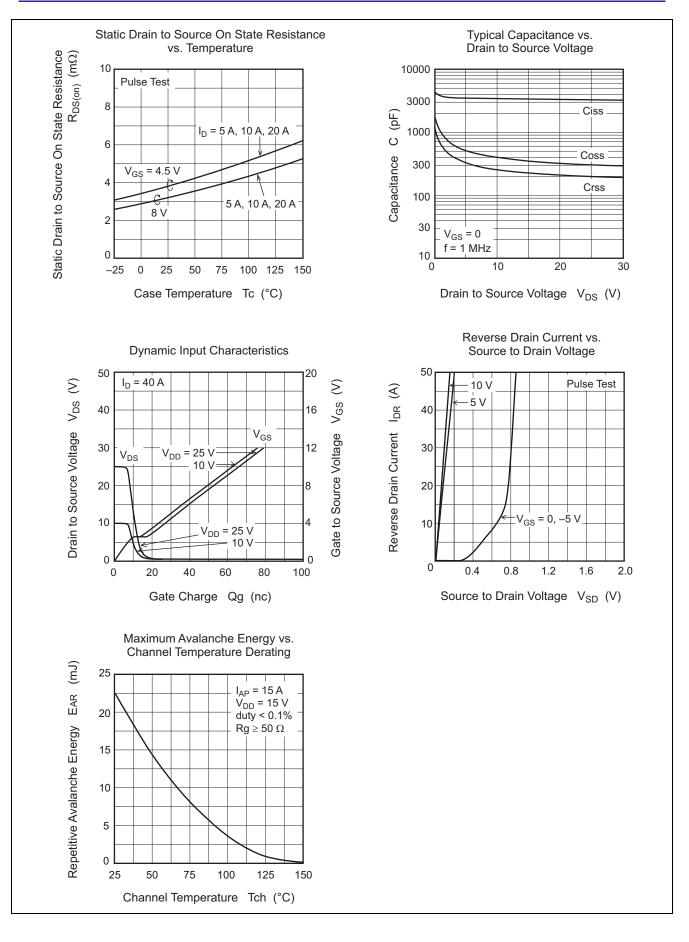
Notes: 4. Pulse test

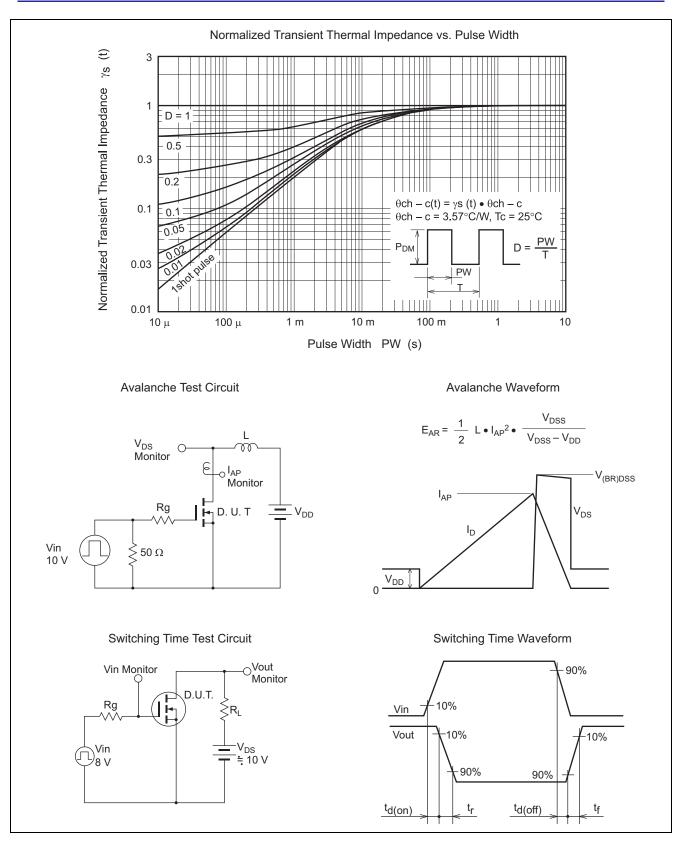


Main Characteristics



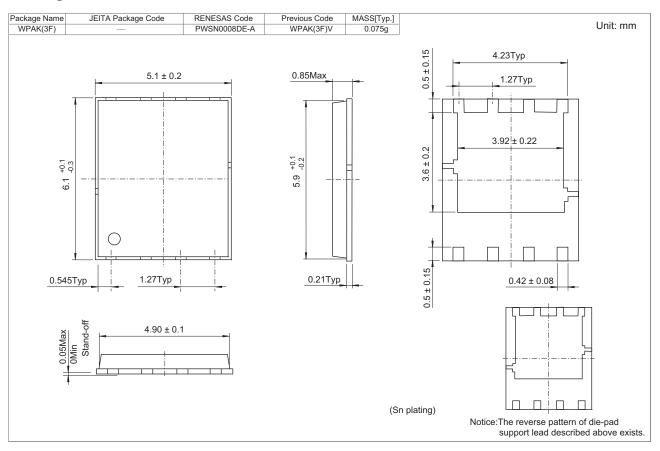








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK03E5DPA-00-J5A	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".



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